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Two-Qubit Gate of Combined Single-Spin Rotation and Interdot Spin Exchange in a Double Quantum Dot

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A crucial requirement for quantum-information processing is the realization of multiple-qubit quantum gates. Here, we demonstrate an electron spin-based all-electrical two-qubit gate consisting of single-spin rotations and interdot spin exchange in a double quantum dot. A partially entangled output state is obtained by the application of the two-qubit gate to an initial, uncorrelated state. We find that the degree of entanglement is controllable by the exchange operation time. The approach represents a key step towards the realization of universal multiple-qubit gates.

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In quantum-information processing, two-qubit gates have the ability to operate on basic algorithms including entanglement control and therefore are essential to test, for example, a controlled-NOT gate [1,2], the EPR paradox [3], or Bell inequalities [4]. Hence, their realization represents a major task in quantum-information processing. Semiconductor quantum dots (QDs), hailed for their potential scalability, are outstanding candidates for solidstate-based quantum-information processing [5]. Here, a single qubit, the smallest logical unit of a quantum circuit, is defined by the two spin states $|\uparrow\rangle$ and $|\downarrow\rangle$, respectively. Single-spin control, crucial for the realization of singlequbit gates, has been demonstrated through magnetically [6] and electrically driven resonance (EDSR) [7–9]. However, two-qubit gates act on four computational basis states denoted by $|\uparrow\rangle|\uparrow\rangle$, $|\uparrow\rangle|\downarrow\rangle$, $|\downarrow\rangle|\uparrow\rangle$, and $|\downarrow\rangle|\downarrow\rangle$. The simplest two-qubit operation suitable to generate entanglement with spin qubits is a "SWAP" one based on the exchange operation [1]. When the interaction between two qubits is turned "on" for a specific duration τ_{ex} , that is, $\tau_{\text{ex}} = \tau_{\text{SWAP}}$, the states $|\uparrow\rangle|\downarrow\rangle$ and $|\downarrow\rangle|\uparrow\rangle$ can be swapped to $|\downarrow\rangle|\uparrow\rangle$ and $|\uparrow\rangle|\downarrow\rangle$, respectively, while $|\uparrow\rangle|\uparrow\rangle$ and $|\downarrow\rangle|\downarrow\rangle$ remain unchanged. A reduction of the operation time by a factor of 2, $\tau_{ex} = \tau_{SWAP}/2$, produces the \sqrt{SWAP} or SWAP^{n=1/2} gate, which has then the maximum entangling capability [10].

The electrical manipulation of exchange in a double QD has been demonstrated with a single singlet-triplet qubit [11]. However, the complete control of entanglement between two electron spins requires systematic manipulations of spin exchange and the possibility to address individual spins. Recently, an optical control of

entanglement between two QD spins with a two-qubit gate has been achieved [12].

In this Letter, we demonstrate an all-electrical two-qubit gate composed of single-spin rotations and interdot spin exchange in a double QD with a novel split micromagnet. The micromagnet generates an inhomogeneous Zeeman field [7,8,13–15] necessary for the qubit operations. We show that (a) the two-qubit gate controls and probes the spin singlet component of the output state with a probability depending on the exchange operation time τ_{ex} and (b) the observed oscillations of the singlet probability with τ_{ex} strongly suggest the control of the degree of entanglement.

Figure 1(a) shows the gate-defined double QD with a split cobalt (Co) micromagnet. A quantum point contact (QPC) is used as a charge sensor [16] to map the charge stability diagram in Fig. 1(b). The charge state change is observed as a change in the QPC transconductance, $G_{\rm QPC} = dI_{\rm QPC}/dV_{\rm PL}$ for the QPC current $I_{\rm QPC}$ and the voltage $V_{\rm PL}$ on the plunger-left (PL) gate. In the region of the stability diagram where $(N_{\rm L}, N_{\rm R}) = (1, 1)$, the double QD contains only two electrons, spatially separate from each other, one in each QD. Here, $N_{\rm L}$ and $N_{\rm R}$ are the number of electrons, for the left and right QD, respectively. Single-spin rotations and interdot spin exchange manipulation are performed in the (1, 1) region, along the detuning lines A, B, and/or C under an external in-plane magnetic field B_0 .

To rotate each electron spin of the double QD, we use EDSR [7–9,13,15,17]. When the micromagnet on top of the double QD is magnetized, well above saturation $(B_0 > 0.5 \text{ T})$, along the *z* direction (M_{Co}) , a stray magnetic



FIG. 1 (color). (a) Scanning electron microscopy image of the device fabricated on top of an AlGaAs/GaAs heterostructure showing the Ti/Au gates (light gray) and the split cobalt (Co) magnet (yellow) separated from the gate contacts by a calixarene layer. Gates R (right) and L (left) control $N_{\rm R}$ and $N_{\rm L}$; C (center) controls the interdot tunnel coupling t. Fast voltage pulses are applied to the Co and PL gates. A MW voltage V_{ac} is applied to the upper part of the magnet. G_{QPC} is measured by modulating the PL gate voltage V_{PL} . (b) Stability diagram (G_{OPC} vs V_{L} and $V_{\rm R}$ applied to the gates L and R, respectively) in the PSB regime $B_0 = 1$ T (no MW). Source (S)-drain (D) bias is 1.5 mV. ε is measured from the $(N_L, N_R) = (0, 2) - (1, 1)$ boundary (dotted line: $\varepsilon = 0$ to the (1, 1) [(0, 2)] region. The dotted line highlights the experimentally obtained region where the lift-off of PSB at EDSR occurs. Schematically further detuning lines labeled B and C are shown. (c) cw EDSR for the left and right spin. PSB is lifted on resonance for the left (red) and right (blue) QD spin ($V_{\rm C} = -1.090$ V, $f_{\rm ac} = 5.6$ GHz). EDSR peak separation: $\Delta B_0 = 15 \pm 5$ mT. The g factor from f_{ac} vs B_0 : g = -0.394 ± 0.001 . (d) Measurement cycle for controlled singlespin rotations with source (S), drain (D), left (L), and right (R)QDs. Repetition period $\sim 9 \ \mu s$ and repeated ~ 100 times.

field at the QD is generated. The stray field is composed of a slanted out-of-plane component $B_{\nu}(z) \left[dB_{\nu}/dzT (\mu m) \right]$ and an inhomogeneous in-plane component $B_{in-plane}(x)$ $(\ll B_0)$ resulting in the Zeeman offset $\delta E_Z = E_{zL} - E_{zR}$ across the two QDs. We spatially displace with electric fields the electrons in the presence of $B_{\nu}(z)$ by applying microwaves (MWs) to the top micromagnet (Co gate). Single-spin rotations occur when the MW frequency $f_{\rm ac}$ matches the local Zeeman field $E_{z\nu=L,R}$ of the left or right QD. We set the QDs in the Pauli spin blockade (PSB) [18] and apply continuous (cw) MW at f_{ac} by sweeping B_0 to measure two resonant peaks [Fig. 1(c)], one for spin rotations in the left QD and the other in the right QD [19]. PSB is established at an interdot energy detuning $\varepsilon = 0$ at point A by the formation of the spin triplet state $[T_{+}(1,1) = |\uparrow\rangle|\uparrow\rangle$ or $T_{-}(1,1) = |\downarrow\rangle|\downarrow\rangle|\downarrow\rangle$ for $(N_{\rm L},N_{\rm R}) =$ (1, 1) only when the Zeeman energy splitting between the triplets $T_{\pm}(1, 1)$ and $T_0(1, 1)$ is larger than the fluctuating



FIG. 2 (color). (a) Rabi oscillations for the left (red) and right (blue) ($B_{0L} = 2$ T and $B_{0R} = 1.985$ T, $V_C = -1.090$ V, $f_{ac} = 11$ GHz). δG_{QPC} is the difference in G_{QPC} between the onresonance and off-resonance conditions with B_0 as a parameter. (b) Rabi oscillation frequency f_{Rabi} as a function of the square root of MW power, $P_{MW}^{1/2}$, for the left (red) and right (blue) QD spin ($B_{0L} = 2$ T and $B_{0R} = 1.985$ T).

nuclear field (a few millitesla) [20]. For PSB due to the spin selection rule $T_{\pm}(1, 1)$ cannot change into the doubly occupied singlet S(0, 2) with $(N_{\rm L}, N_{\rm R}) = (0, 2)$, and thereby current is blocked. However, EDSR can lift off PSB with a spin rotation from $T_{+}(1, 1)$ [or $T_{-}(1, 1)$] to $|\downarrow\rangle|\uparrow\rangle$ or $|\uparrow\rangle|\downarrow\rangle$, followed by a transition to S(0, 2). Note that $T_{0}(1, 1)$ is strongly hybridized to the singlet S(1, 1) state by the Zeeman field gradient and so is not subject to the blockade effect [7,8].

The control of specific spin rotations around the x axis with a rotation angle θ , in the Bloch sphere, is presented by measuring Rabi oscillations for both spins. Therefore, we set B_0 at each cw EDSR peak with $f_{ac} = 11.1$ GHz: $B_{0L} = 2$ T and $B_{0R} = 1.985$ T for the left and right QDs, respectively. Furthermore, we apply voltage pulses nonadiabatically to Co and PL gates to change ε [21]. In particular, we switch between two operation stages A ($\varepsilon = 0$) and B ($\varepsilon \approx 277 \ \mu eV$, $\varepsilon \gg 0$) [Fig. 1(d)]. At stage A, in the PSB the two-electron state is initialized to either $T_{-}(1, 1)$ or $T_{+}(1, 1)$. Here, finite interdot tunnel coupling t is present. However, in stage B where the exchange energy is negligible we perform controlled spin rotations with a rotation angle θ by applying pulsed MWs with a duration τ_{EDSR} . Finally, the readout at stage A allows the left electron to tunnel to the right dot with the probability depending on the spin rotation angle. The cycle [Fig. 1(d)] of $A \rightarrow B \rightarrow A$ is repeated continuously and lift-off of PSB at a given cycle modifies the average charge seen by the QPC. The averaged QPC signal is thus proportional to the probability of having antiparallel spins $|\downarrow\rangle|\uparrow\rangle$ or $|\uparrow\rangle|\downarrow\rangle$. In Fig. 2(a), we then detect the averaged QPC signal, which oscillates as a function of τ_{EDSR} . The oscillations reveal a linear scaling of the oscillation frequency

upon the square root of the MW power $P_{\rm MW}$ or driving ac electric field amplitude for the left and right spins [Fig. 2(b)], a characteristic feature of Rabi oscillations [8]. $f_{\rm Rabi}$ is higher for the left QD and so is the state fidelity reflecting a larger field gradient and MW field [21].

Next we prepare a two-qubit gate comprising controlled left spin x rotations and interdot spin exchange between the QDs as illustrated in Fig. 3(a). We choose specific rotation angles for the left spin using pulsed MWs at $B_{0L} = 2$ T. The interdot spin exchange operation is operated by manipulating the interdot exchange energy J_0 [1]. J_0 is defined as energy difference between the singlet S(1, 1)and the triplet state $T_0(1, 1)$ and depends strongly on the relative energy detuning ε of S(0, 2) and S(1, 1). It becomes large in the vicinity of zero detuning and vanishes for large detuning. To change ε or J_0 we apply voltage pulses to PL and Co gates, establishing three quantum stages, namely, A, B, and C [Fig. 3(a)]. The operation starting at stage A either with $T_+(1, 1)$ or $T_-(1, 1)$ for $\varepsilon = 0$ eV evolves by

$$T_{\pm}(1,1) \xrightarrow{L(3\pi/2)} \frac{|\uparrow\rangle \pm |\downarrow\rangle i}{\sqrt{2}} \otimes |\uparrow\rangle \xrightarrow{J_0:\tau_{\rm ex}} |\psi_1\rangle \xrightarrow{L(\pi/2)} |\psi_2\rangle, \quad (1)$$

where $L\frac{3\pi}{2}$ and $L\frac{\pi}{2}$ in stage *B* represent the specific $\frac{3\pi}{2}$ and $\frac{\pi}{2}$ rotations, respectively, around the *x* axis. At stage *B* the interdot tunneling and therefore J_0 are negligible for $\varepsilon \approx 277 \ \mu \text{eV}$. The quantum operation $J_0:\tau_{\text{ex}}$ at stage *C*



FIG. 3 (color). (a) Cycle of the two-qubit gate operation with source (*S*), drain (*D*), left (L), and right (R) QDs. (b) Result of two-qubit measurement for $\varepsilon = 27.70$ (*A*), 55.40 (*B*), 83.10 (*C*), and 138.50 (*D*) ($V_{\rm C} = -1.0845$ V, $f_{\rm Rabi} = 1.2$ MHz, $B_0 = 2$ T). Contour plot showing J_0 vs $\tau_{\rm ex}$ indicating $P_{\rm S}$. We use the ratio $\delta E_Z/J_0$ as a fitting parameter to reproduce the experimental data and find that all data (*A*) to (*D*) measured for various detuning values are consistent with the calculation by taking $\delta E_Z/J_0 \approx 0.74$ (SWAP^{*n*=1,3,5,...,} red; NOP, black). $f_{\rm Rabi} = 1.2$ MHz and the nuclear spin variance for the left and right spins is 0.275 ± 0.025 MHz. Clear dependence on $\tau_{\rm ex}$ and ε is demonstrated with $\delta E_Z/J_0 = 0.69$ (*A*), 0.73 (*B*), 0.78 (*C*), and 0.77 (*D*), which gives on average 0.74. Yellow solid curves represent $P_{\rm S}$ for (*A*)–(*D*) vs $\tau_{\rm ex}$. Curves are offset for clarity.

represents the two-qubit exchange operation. Here, for $\varepsilon \rightarrow 0$, e.g., 27.70 μeV , the exchange is controlled by the operation time or hold time τ_{ex} . $|\psi_1\rangle$ is then the two-qubit state after the controlled rotation $L\frac{3\pi}{2}$ and exchange operation. After $L\frac{\pi}{2}$, $|\psi_1\rangle$ is finally transformed to the output state $|\psi_2\rangle$. Note that the state fidelity of the two single-spin rotations in stage B $\left(L\frac{3\pi}{2}\right)$ and $L\frac{\pi}{2}$ strongly influences that of the presented two-qubit gate operation [21]. The cycle A through C is repeated continuously. Assuming an initialization to $T_{+}(1, 1)$, the wave function at the output controlled by $\tau_{\rm ex}$ is, e.g., $|\psi_2\rangle = T_+(1, 1)$ for no exchange operation (NOP = SWAP^{*n*=0,2,4,...}) and $|\psi_2\rangle = \frac{1}{2}[T_+(1,1) +$ $T_{-}(1, 1) - \sqrt{2}iS(1, 1)$ for SWAP^{n=1,3,5,...}. The single-spin rotation angles are chosen such that $|\psi_2\rangle$ has only T_{\pm} and S components irrespective of the initial state $(T_+ \text{ or } T_-)$. Because of PSB the triplets $T_{\pm}(1, 1)$ themselves do not bring about the change of charge; only the singlet component of the output state gives rise to charge transitions [from (1, 1) to (0, 2)] at the readout stage [22]. The charge sensor readout is thereby a direct measurement of the probability $P_S = |\langle S | \psi_2 \rangle|^2$. Therefore, in the case of SWAP^{*n*=1,3,5,...}, only $\sqrt{2}iS(1,1)$ is probed in $|\psi_2\rangle$. However, for NOP no charge transfer is detected resulting in a minimum of the QPC signal. In Fig. 3(b), we plot the change of the charge state measured by the QPC as a function of au_{ex} and detuning ε or J_0 . The measurement exhibits periodic oscillations as a function of both parameters. The experimental data agree well with a model calculation of P_{S} [21]. The model includes the effect of finite δE_Z and nuclear field fluctuations [15]. Maxima in Fig. 3(b) appear when the exchange operation is SWAP^{*n*=1,3,5,...} for $\tau_{ex} = (2k + 1)\tau_{SWAP}$ and minima when $\tau_{\rm ex} = k \tau_{\rm NOP}$ with $\tau_{\rm NOP} = 2 \tau_{\rm SWAP}$, where k = 0, 1, 2, ... for NOP. SWAP^{n=1/2} is obtained for $\tau_{\rm ex} = \tau_{\rm SWAP}/2$. That is, the two-qubit gate combined with PSB enables the control and detection of the singlet component in the output state with the finding probability depending on the exchange operation time τ_{ex} . Using the model calculation allows us to extract the operation time τ_{SWAP} for SWAPⁿ⁼¹, defined as half the oscillation period. In Fig. 4(a), we investigate the dependence of $\tau_{\rm SWAP}^{-1}$ on ε . As expected, $\tau_{\rm SWAP}$ is getting shorter with decreasing t [1]. In addition, the inset in Fig. 4(a) shows the effect of interdot tunnel coupling t on $\tau_{\rm SWAP}$. Note that the exchange energy depends on ε and t, where $t \approx \sqrt{(1/2)J_0\varepsilon}$, for $\varepsilon \gg t > \delta E_Z$ [23,24]. The data points in Fig. 4(a) are reproduced only if we assume δE_Z to be varying linearly with ε [21]. J_0 defined by the oscillation period and δE_Z obtained from the fit in Fig. 4(a) yield a ratio $\delta E_Z/J_0$ necessary for the calculated P_S to resemble the experimental data in Fig. 3(b).

Finally, to evaluate the degree of entanglement between the two electron spins we calculate the concurrence C [25] for the output state $|\psi_2\rangle$ [21] as a function of τ_{SWAP} . For maximally entangled qubits $C(\tau_{\text{ex}}) = 1$, and for uncorrelated qubits $C(\tau_{\text{ex}}) = 0$. The analytical expression of C by



FIG. 4 (color). (a) τ_{SWAP}^{-1} , as a function of ε for different tunnel coupling. Blue: $V_{\text{C}} = -1.082 \text{ V}$ ($t = 1.13 \pm 0.1 \ \mu \text{eV}$). Red: -1.0845 V ($t = 0.98 \pm 0.1 \ \mu \text{eV}$). Solid curves: Fits for a linearly varying Zeeman gradient, $\Delta B_0 \equiv B_{0\text{L}} - B_{0\text{R}} = a + b\varepsilon$, with g = -0.4. Fitting parameters a and b are assumed to be independent of V_{C} [$a = -7.1 \pm 0.4 \text{ mT}$, $b = -24.4 \pm 3 \text{ T/eV}$, and $t = 1.13 \pm 0.1 \ \mu \text{eV}$ ($t = 0.98 \pm 0.1 \ \mu \text{eV}$)]. As expected, the V_{C} primarily controls t. Inset: τ_{SWAP} obtained for $\varepsilon = 27.70 \pm 1.50 \ \mu \text{eV} \text{ vs } t$ for $V_{\text{C}} = -1.081, -1.082, -1.083, -1.0845$, and -1.086 V; (from right to left), $\varepsilon = \text{const.}$ The shortest τ_{SWAP} obtained here is $\approx 10 \text{ ns.}$ (b) C vs τ_{ex} and J_0 for the average ratio $\delta E_Z/J_0 = 0.74$ used for the P_{S} calculation. C = 50% for maximum entanglement at $\tau_{\text{ex}} = \tau_{\text{SWAP}}(2k + 1)/2$, $k = 0, 1, 2, \dots$

neglecting nuclear spin fluctuations but including the effect of δE_Z is given by

$$\mathcal{C} = \frac{|\sin\sqrt{1 + \Delta^2 \alpha}|}{1 + \Delta^2} \times \sqrt{(1 + \Delta^2)\cos^2\sqrt{1 + \Delta^2 \alpha} + \Delta^2 \sin^2\sqrt{1 + \Delta^2 \alpha}} \quad (2)$$

with $\Delta \equiv \delta E_Z/J_0$ and $\alpha \equiv J_0 \tau_{ex}/2$ [21]. Figure 4(b) shows the calculated C as a function of τ_{ex} and J_0 . C of $|\psi_1\rangle$ [21] is zero at, e.g., $\tau_{ex} = 0$ and τ_{swap} or maximal (C = 1/2) for $swap^{n=1/2}$ at $\tau_{ex} = \tau_{swap}/2$ when $\delta E_Z = 0$ [25]. When $\delta E_Z \neq 0$, the τ_{ex} dependence of Cis slightly modified by reducing the maximal value of C[21]. However, the calculated C in comparison with the observed P_S gives evidence for the control of the degree of entanglement with τ_{ex} .

We have demonstrated an all-electrical two-qubit gate comprised of controlled single-spin rotations and spin exchange in a double quantum dot. Therefore, we used a micromagnet to drive spin rotations under ac electric fields and voltage pulses to control the exchange interaction. The two-qubit gate generates a singlet component in the output state, which is probed directly by charge sensing. In addition, we calculated the degree of entanglement by using the parameters derived from the experiment. Finally, we propose that with faster single-spin rotations the two-qubit gate implemented here would be highly suitable to test in future experiments the controlled NOT gate [1,2], the EPR paradox [3], or Bell inequalities [4].

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